EPISTAR

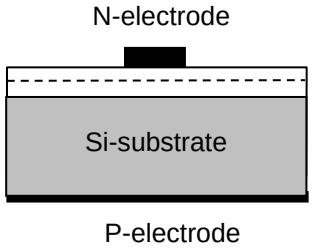
ES-SASFDN30E

AIGaAs DN-series LED Chip

> Mechanical Specification:

(1) Dimension
- Chip size: 30 mil x 30 mil (762±25 µm x 762±25 µm)
- Thickness: 6.7 mil (170±25 µm)
- N bonding pad: 6.3 mil (160±10 µm)

(2) Metallization
- Topside N electrode : Au alloy
- Backside P electrode: Au alloy



Features:
- High radiant flux
- Thin film structure
- Vertical electrode
- High driving current

Applications:
- Face Recognition
- Data Communication
- Surveillance

> Electro-optical Characteristics at 25°C:

Parameter	Symbol		Condition	Min.	Typ.	Max.	Unit
Forward Voltage	Vf1		If = 10µA	1.4	-	-	V
	Vf2		If = 500mA	-	3.1	3.3	V
Reverse Current	Ir		Vr = 10V	-	-	5.0	µA
Peak Wavelength[1]	λp		If = 500mA	840	855	870	nm
Spectra Half-width	Δλ		If = 500mA	-	35	-	nm
Radiant flux[2][3]	Po	C20	If = 500mA	470	-	-	mW
		C21		520	-	-	
		C22		580	-	-	

Note:
(1) Basically, the wavelength span is 30nm; however, customers' special requirements are also welcome.
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(3) Radiant flux is measured by EPISTAR's equipment on bare chips.

> Absolute Maximum Ratings:

Parameter	Symbol	Condition	Rating	Unit
Forward DC Current	If	Ta = 25˚C	≤ 800	mA
Reverse Voltage	Vr	Ta = 25˚C	≤ 10	V
Junction Temperature	Tj	-	≤ 145	˚C
Storage Temperature	Tstg	Chip	-40 ~ +85	˚C
		Chip-on-tape/storage	5 ~ 35	˚C
		Chip-on-tape/transportation	-20 ~ +65	˚C
Temperature during Packaging	-	-	280(<10sec)	˚C

Note: Maximum ratings are package dependent. The above maximum ratings were determined using a Metal Core Printed Circuit Board (MCPCB) without an encapsulant. Stresses in excess of the absolute maximum ratings such as forward current and junction temperature may cause damage to the LED.

> Characteristic Curves:

Fig.1 – Relative Radiant Flux vs. Forward Current

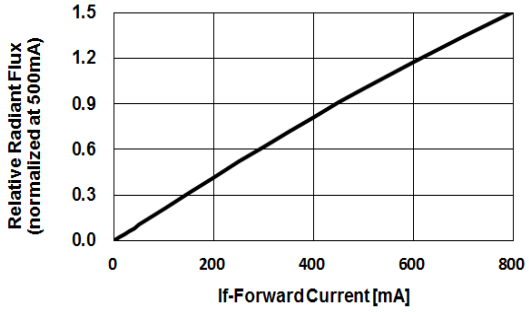

Fig.2 – Forward Current vs. Forward Voltage

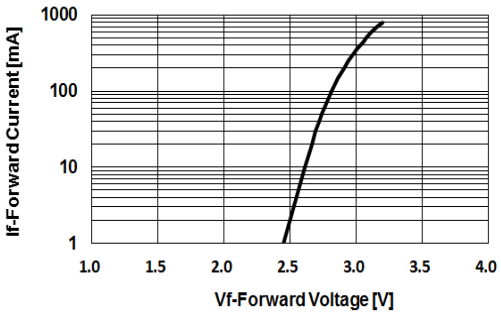

Fig.3 – Relative Radiant Flux (@500mA) vs. Ambient Temperature

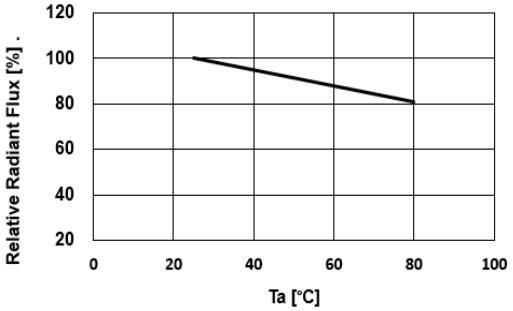

Fig.4 – Forward Voltage (@500mA) vs. Ambient Temperature

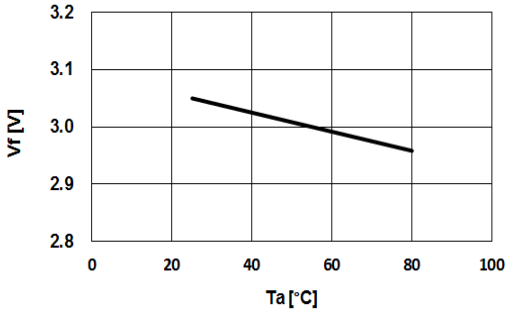

Fig.5 – Peak Wavelength (@500mA) vs. Ambient Temperature

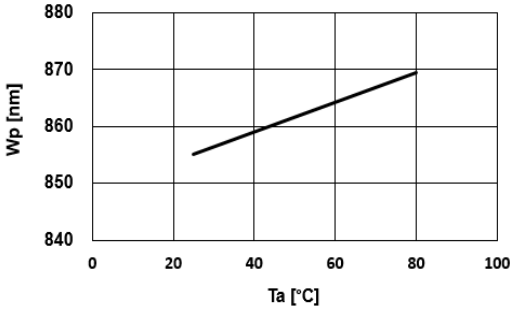

Fig.6 – Maximum Driving Forward DC Current vs. Ambient Temperature (De-rating based on Tj max. = 145°C)